Vishay General Semiconductor

# **Dual High Voltage Trench MOS Barrier Schottky Rectifier**

Ultra Low  $V_F = 0.58$  V at  $I_F = 5$  A



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V20M120M -> PIN 1 O I PIN 2

CASE

PRIMARY CHARACTERISTICS				
I <sub>F(AV)</sub>	2 x 10 A			
V <sub>RRM</sub>	120 V			
I <sub>FSM</sub>	110 A			
V <sub>F</sub> at I <sub>F</sub> = 10 A (T <sub>A</sub> = 125 °C)	0.68 V			
T <sub>J</sub> max.	175 °C			
Package	TO-220AB			
Diode variations	Common cathode			

### **FEATURES**

- Trench MOS Schottky technology
- Low forward voltage drop, low power losses
- · High efficiency operation
- Solder dip 275 °C max. 10 s, per JESD 22-B106 RoHS
- · Material categorization: for definitions of COMPLIANT compliance please see www.vishay.com/doc?99912

## TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection.

## **MECHANICAL DATA**

#### Case: TO-220AB

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade

Terminals: Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

<b>MAXIMUM RATINGS</b> ( $T_A = 25 \text{ °C}$ unless otherwise noted)					
PARAMETER		SYMBOL	V20M120M	UNIT	
Maximum repetitive peak reverse voltage		V <sub>RRM</sub>	120	V	
Maximum average forward rectified current (fig. 1)	per device	I <sub>F(AV)</sub>	20	А	
	per diode		10		
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load		I <sub>FSM</sub>	110	А	
Voltage rate of change (rated V <sub>R</sub> )		dV/dt	10 000	V/µs	
Operating junction and storage temperature range		T <sub>J</sub> , T <sub>STG</sub>	-55 to +175	°C	

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<b>ELECTRICAL CHARACTERISTICS</b> ( $T_A = 25$ °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT	
Instantaneous forward voltage per diode	I <sub>F</sub> = 5 A	- T <sub>A</sub> = 25 °C	V <sub>F</sub> <sup>(1)</sup>	0.70	-	V	
	I <sub>F</sub> = 10 A			0.93	1.01		
	I <sub>F</sub> = 5 A	– T <sub>A</sub> = 125 °C		0.58	-		
	I <sub>F</sub> = 10 A			0.68	0.76		
Reverse current per diode	V <sub>R</sub> = 100 V	T <sub>A</sub> = 25 °C	I <sub>R</sub> (2)	2.0	-	μA	
		T <sub>A</sub> = 125 °C		1.5	-	mA	
	$V_{-} = 120 V_{-}$	T <sub>A</sub> = 25 °C		-	500	μA	
	V <sub>R</sub> = 120 V	T <sub>A</sub> = 125 °C		2.0	12	mA	

#### Notes

 $^{(1)}\,$  Pulse test: 300  $\mu s$  pulse width, 1 % duty cycle

<sup>(2)</sup> Pulse test: Pulse width  $\leq$  5 ms

<b>THERMAL CHARACTERISTICS</b> ( $T_A = 25 \text{ °C}$ unless otherwise noted)				
PARAMETER		SYMBOL	V20M120M	UNIT
Typical thermal resistance	per diode	R <sub>θJC</sub>	2.8	°C/W
	per device		1.4	
	per device	R <sub>0JA</sub> (1)(2)	40	

#### Notes

<sup>(1)</sup> The heat generated must be less than the thermal conductivity from junction-to-ambient  $dP_D/dT_J < 1/R_{\theta JA}$ 

<sup>(2)</sup> Free air, without heatsink

ORDERING INFORMATION (Example)							
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
TO-220AB	V20M120M-E3/4W	1.88	4W	50/tube	Tube		

### RATINGS AND CHARACTERISTICS CURVES (T<sub>A</sub> = 25 °C unless otherwise noted)

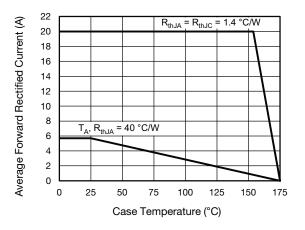


Fig. 1 - Maximum Forward Current Derating Curve

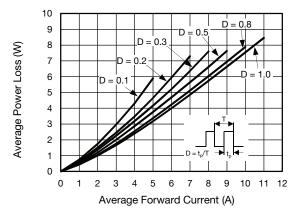
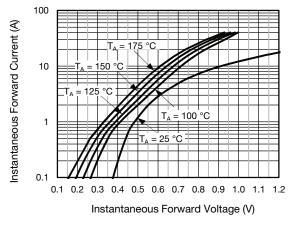


Fig. 2 - Forward Power Loss Characteristics Per Diode

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Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

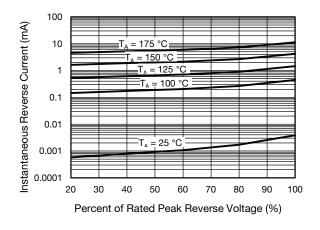


Fig. 4 - Typical Reverse Characteristics Per Diode

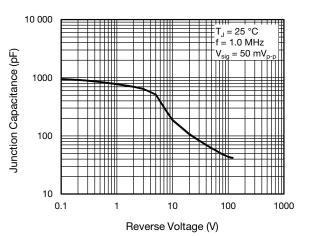


Fig. 5 - Typical Junction Capacitance Per Diode

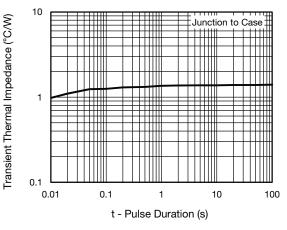
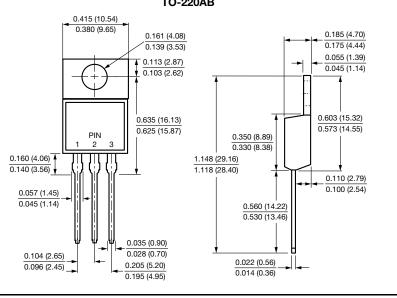


Fig. 6 - Typical Transient Thermal Impedance Per Device

# **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)



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 3
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TO-220AB



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